

Product data sheet

1 General description

NPN general-purpose transistors in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

PNP complements: BCW68F/G/H

2 Features and benefits

- High current
- AEC-Q101 qualified

3 Applications

• General-purpose switching and amplification

4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base		-	-	45	V
I _C	collector current			-	-	800	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-	1	А
h _{FE}	DC current gain	V_{CE} = 1 V; I _C = 100 mA; T _{amb} = 25 °C	[1]				
	BCW66F			100	-	250	
	BCW66G			160	-	400	
	BCW66H			250	-	600	

[1] pulsed: $t_p \le 300 \ \mu s, \ \delta \le 0.02$



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5 Pinning information

Table 2. Pinning							
Pin	Symbol	Description	Simplified outline	Graphic symbol			
1	В	base					
2	E	emitter		C I			
3	C	collector		B E sym123			

6 Ordering information

Table 3. Ordering iType number	Package		
	Name	Description	Version
BCW66F	TO-236AB	plastic surface-mounted package; 3 leads	SOT23
BCW66G			
BCW66H			

7 Marking

Table 4. Marking

Type number		Marking code
BCW66F	[1]	EQ%
BCW66G	[1]	ER%
BCW66H	[1]	ES%

[1] % = placeholder for manufacturing site code

8 Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter	-	50	V
V _{CEO}	collector-emitter voltage	open base	-	45	V
V _{EBO}	emitter-base voltage	open collector	-	5	V
I _C	collector current		-	800	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms	-	1	А
I _B	base current		-	100	mA

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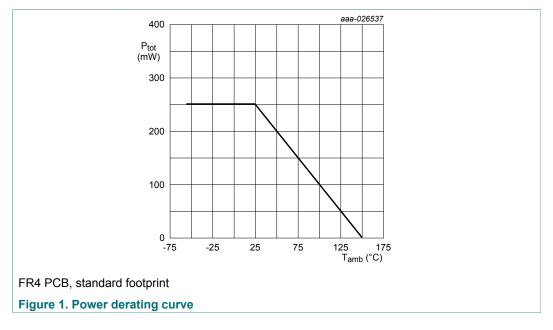
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Symbol	Parameter	Conditions		Min	Мах	Unit
I _{BM}	peak base current	single pulse; t _p ≤ 1 ms		-	200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	250	mW
Тj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit-Board (PCB), single-sided chopper, tin-plated and standard footprint.



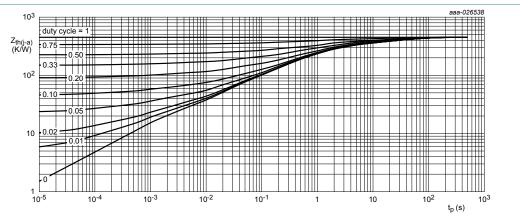
9 Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	-	500	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

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FR4 PCB, standard footprint

Figure 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

10 Electrical characteristics

Table 7. Electrical characteristics

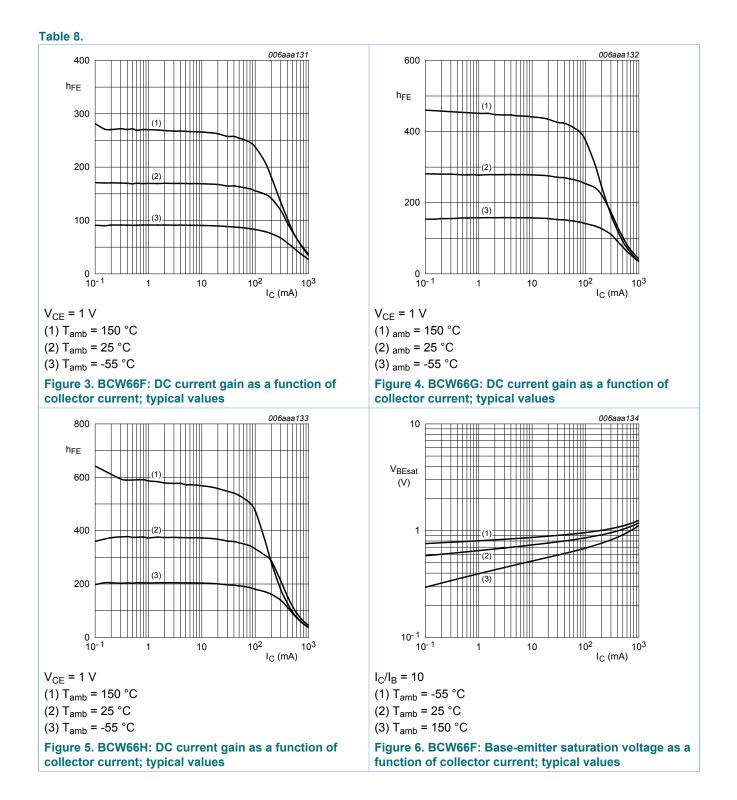
T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
сво	collector-base	V _{CB} = 40 V; I _E = 0 A		-	-	20	nA
	cut-off current	V _{CB} = 40 V; I _E = 0 A; T _j = 150 °C		-	-	5	μA
ЕВО	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A		-	-	20	nA
٦ _{FE}	DC current gain						
	BCW66F/G/H	V_{CE} = 1 V; I _C = 100 µA		75	-	-	
	BCW66F/G/H	V _{CE} = 1 V; I _C = 1 mA		75	-	-	
	BCW66F/G/H	V _{CE} = 1 V; I _C = 10 mA		75	-	-	
	BCW66F	V _{CE} = 1 V; I _C = 100 mA	[1]	100	-	250	
	BCW66G		[1]	160	-	400	
	BCW66H		[1]	250	-	630	
	BCW66F/G/H	V _{CE} = 1 V; I _C = 500 mA	[1]	40	-	-	
V _{CEsat}	collector-emitter	I _C = 100 mA; I _B = 10 mA	[1]	-	-	350	mV
	saturation voltage	I _C = 500 mA; I _B = 50 mA	[1]	-	-	450	mV
V _{BEsat}	base-emitter	I _C = 100 mA; I _B = 10 mA	[1]	-	-	1.25	V
	saturation voltage	I _C = 500 mA; I _B = 50 mA	[1]	-	-	1.25	V
f _T	transition frequency	V_{CE} = 5 V; I _C = 10 mA; f = 100 MHz		100	-	-	MHz
C _c	collector capacitance	V _{CB} = 10 V; I _E = i _e = 0 A; f = 1 MHz		-	3	-	pF

[1] pulsed; $t_p \le 300 \ \mu s$; $\delta \le 0.02$

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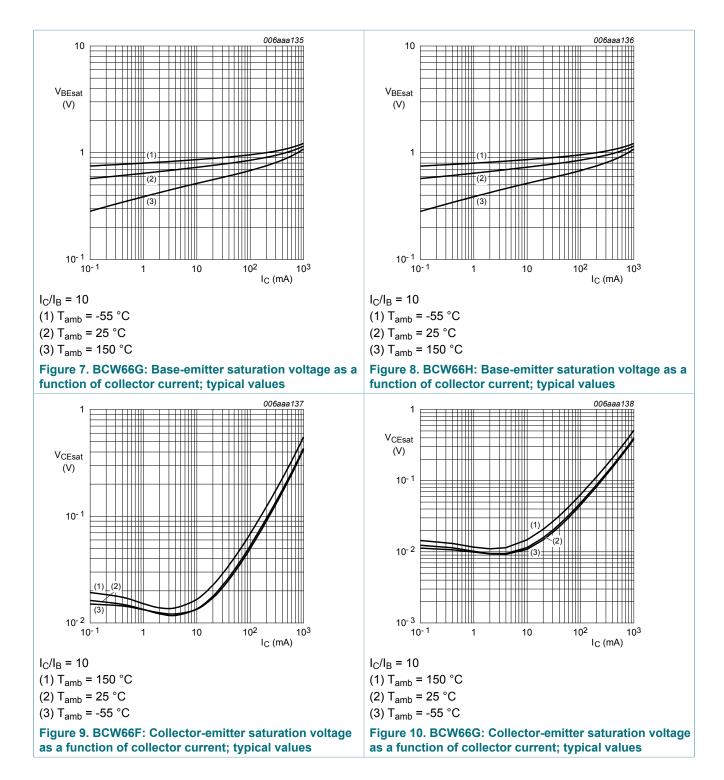
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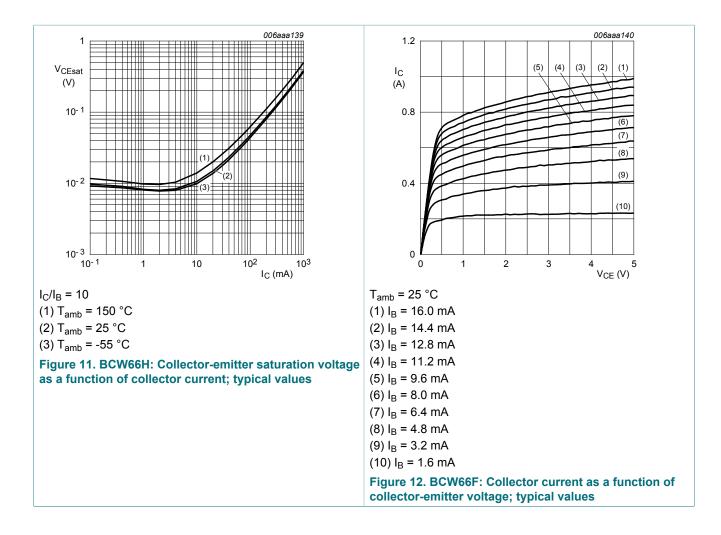
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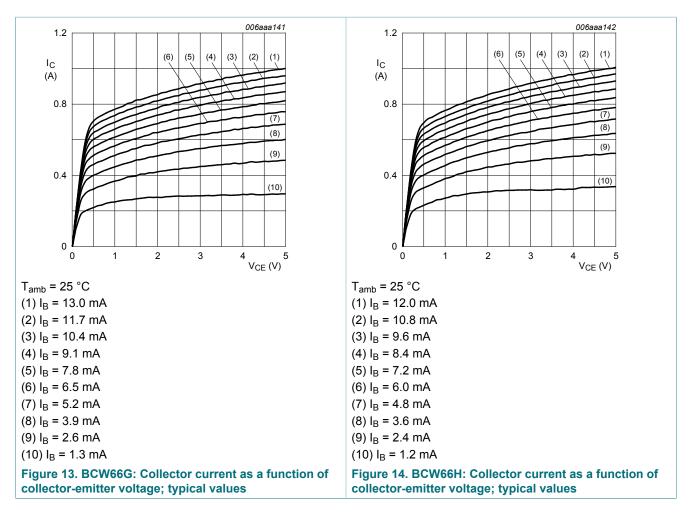
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11 Test information

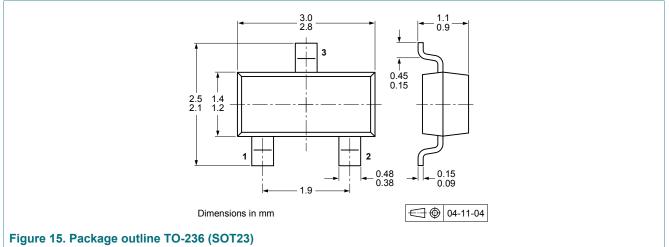
11.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

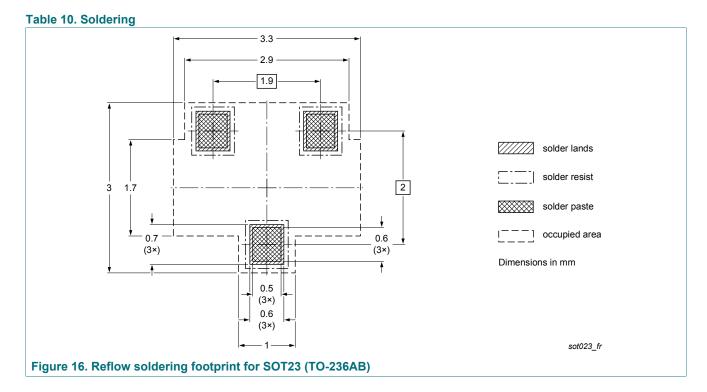
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12 Package outline

Table 9. Package outline

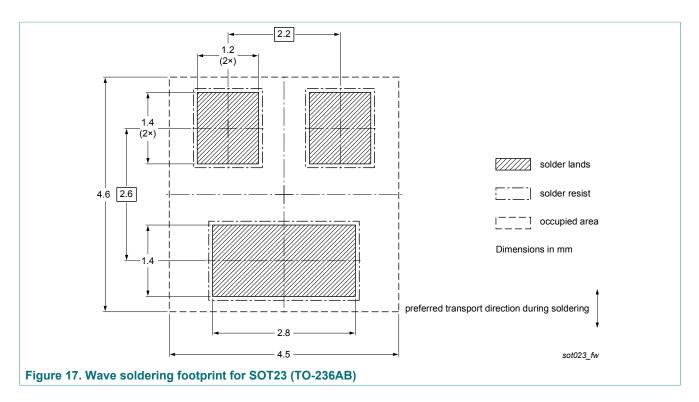


13 Soldering



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14 Revision history

Table 11. Revision history

Document ID		Data sheet status	Change notice	Supersedes
BCW66x_SER v.1	21 April 2017	Product data sheet	-	-

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15 Legal information

15.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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BCW66x SER **Product data sheet**

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